

L4938N/ND L4938NPD

DUAL MULTIFUNCTION VOLTAGE REGULATOR

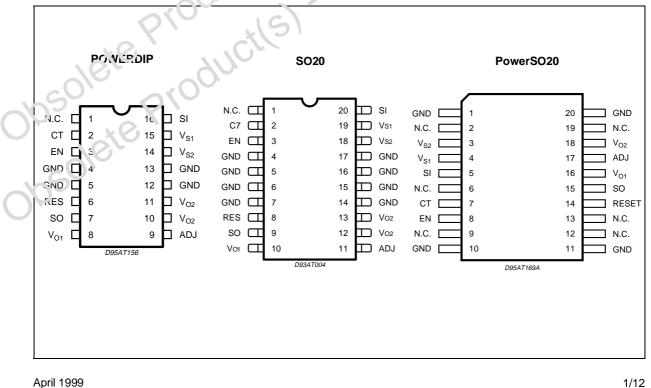
- STANDBY OUTPUT VOLTAGE PRECISION 5V ± 2%
- OUTPUT 2 TRACKED TO THE STANDBY OUT-PUT
- OUTPUT 2 DISABLE FUNCTION FOR STANDBY MODE
- VERY LOW QUIESCENT CURRENT, LESS THAN 250µA, IN STANDBY MODE
- OUTPUT 2 VOLTAGE SETTABLE FROM 5 TO 20V
- OUTPUT CURRENTS : I₀₁ = 50mA, I₀₂ = 500mA
- VERY LOW DROPOUT (max 0.4V/0.6V)
- OPERATING TRANSIENT SUPPLY VOLTAGE UP TO 40V
- POWER-ON RESET CIRCUIT SENSING THE STANDBY OUTPUT VOLTAGE
- POWER-ON RESET DELAY PULSE DEFINED BY THE EXTERNAL CAPACITOR
- EARLY WARNING OUTPUT FOR SUPPLY UN-DERVOLTAGE
- THERMAL SHUTDOWN AND SHORT CIRCUIT PROTECTIONS



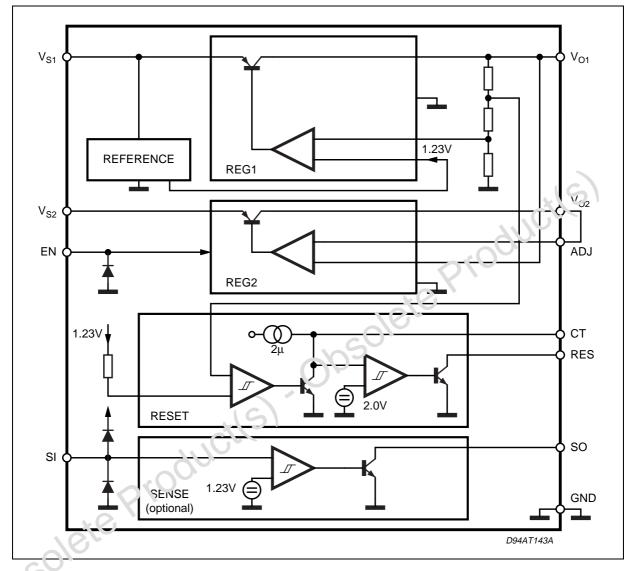
DESCRIPTION

The L4938N is a monolithic integrated dual voltage regulators within we very low dropout outputs and additional the cross such as power-on reset and input voltage sense. They are designed for supplying micross-mputer controlled systems specially in autoinclive applications.

PIN CONNECTION (top view)



BLOCK DIAGRAM



IT'ERMAL DATA

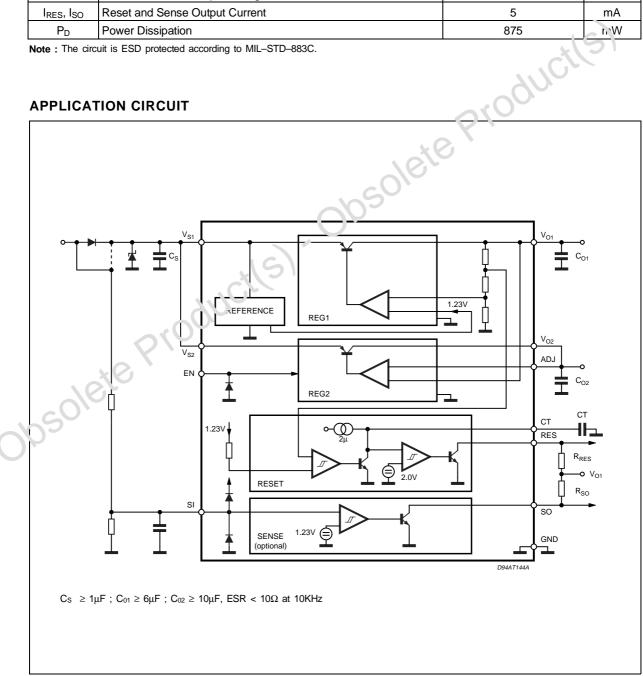
Symbol	Parameter		Powerdip	PowerSO20	SO20	Unit
R _{thj-case}	Thermal Resistance Junction-Case	Max.	14	< 2	_	°C/W
R _{thj-amb}	Thermal Resistance Junction-Ambient	Max.	90	-	20	°C/W

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
Vs	DC Supply Voltage	28	V
	Transient Supply Voltage (T < 1s)	40	V
Tj, T _{stg}	Junction and Storage Temperature Range	–55 to 150	°C
I _{SI}	Sense Input Current ($V_{SI} \leq 0.3V$ or $V_{SI} > V_{S}$)	±1	mA
I _{EN}	Enable Input Current (V _{EN} ≤0.3V)	±1	mA
V _{EN}	Enable Input Voltage	Vs	
$V_{\text{RES}}, V_{\text{SO}}$	Reset and Sense Output Voltage	20	V
I _{RES} , I _{SO}	Reset and Sense Output Current	5	mA
PD	Power Dissipation	875	n:W

 $\ensuremath{\text{Note}}$: The circuit is ESD protected according to MIL-STD-883C.

APPLICATION CIRCUIT



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Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
Vs	Operating Supply Voltage				25	V
V _{O1}	Standby Output Voltage	$\begin{array}{l} 6V \leq \; V_S \leq 25V \\ 1mA \leq I_{O1} \leq 50mA \end{array}$	4.90	5.00	5.10	V
V ₀₂ - V ₀₁	$\begin{array}{llllllllllllllllllllllllllllllllllll$		-25		+25	mV
I _{ADJ}	ADJ Input Current	I _{O1} = 1mA; I _{O2} = 5mA	-1	0.1	1	μA
V _{DP1}	Dropout Voltage 1	I _{O1} = 10mA I _{O1} = 50mA		0.1 0.2	0.25 0.4	V V
V _{IO1}	Input to Output Voltage Difference in Undervoltage Condition	VS = 4V, I _{O1} = 35mA			0.4	5 V
V_{DP2}	Dropout Voltage 2	IO1 = 100mA I _{O1} = 500mA		<u>).?</u>).?	0.3 0.6	V V
V _{IO2}	Input to Output Voltage Difference in Undervoltage Condition	VS = 4.6V, I _{O1} = 350mA	61		0.6	V
V _{OL 1.2}	Line Regulation	$6V \le V_S \le 25V$ $I_{O1} = 1mA; I_{O2} = 5mA.$			20	mV
V _{OLO1}	Load Regulation 1	$1 \text{mA} \le I_{O1} \le 50 \text{m}$			25	mV
V _{OLO2}	Load Regulation 2	$5\text{mA} \leq I_{C,2} \leq 500\text{m/A}$			50	mV
I _{LIM1}	Current Limit 1	V _{O1} = 4.5 ′ V _{O1} = 0V (note 2)	55 25	100 50	200 100	mA mA
I _{LIM2}	Current Limit 2	VC 2 = 0V	550	1000	1700	mA
I _{QSB}	Quiescent Current Standby Mode (output 2 disabled)	$I_{O1} = 0.3$ mA; $T_J < 100^{\circ}$ C $V_{EN} \ge 2.4$ V $V_S = 14$ V $V_S = 3.5$ V		210 340	290 850	μΑ μΑ
lQ	Quiescont Durrent	I _{O1} = 50mA I _{O1} = 500mA			30	mA

ELECTRICAL CHARACTERISTICS (V_S = 14V; $-40^{\circ}C \le T_J \le 125^{\circ}C$ unless otherwise specified)

ENABLE

VLINL	Enable Input LOW Voltage (output 2 active)		-0.3		1.5	V
V _{ENH}	Enable Input HIGH Voltage		2.4		7	V
V _{ENhyst}	Enable Hysteresis		30	75	200	mV
I _{EN}	Enable Input Current	$0V < V_{EN} < 1.2V$ 2.5V < $V_{EN} < 7V$	-10 -1	-1.5 0	-0.5 +1	μΑ μΑ

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ELECTRICAL CHARACTERISTICS (continued)

RESET

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{Rt}	Reset Low Threshold Voltage		V _{o1} -0.4	4.7	V _{o1} -0.1	V
V _{Rth}	Reset Threshold Hysteresis		50	100	200	mV
t _{RD}	Reset Pulse Delay	$C_{T} = 100 nF; t_{R} > 100 \mu s$	55	100	180	mV
t _{RR}	Reset Reaction Time	C _T = 100nF	1	10	50	μs
V _{RL}	Reset Output LOW Voltage	R_{RES} = 10K Ω to V ₀₁ V _S = 1.5V			0.4	V
I _{LRES}	Reset Output HIGH Leakage	$V_{RES} = 5V$			1	uА
V _{CTh}	Delay Comparator Threshold			2.0		
V _{CTh, hyst}	Delay Comparator Threshold Hysteresis			100	C	mV

SENSE

SENSE			25	20,0		
V _{Slth}	Sense Threshold Voltage		.16	1.23	1.35	V
V _{Slth, hyst}	Sense Threshold Hysteresis	*0	40	100	200	mV
V _{SOL}	Sense Output LOW Voltage	$\label{eq:VSI} \begin{array}{l} V_{SI} = 1,16V; \ V_S \geq 3V \\ R_{SO} = 10K\Omega \ to \ V_{01} \end{array}$			0.4	V
I _{LSO}	Sense Output Leakage	$V_{SO} = 5V; V_{S_1} \ge 1.5V$			1	μA

Note: 1: Vo2 connected to ADJ.Vo2 can be set to higher values by inse ting an external resistor divider.

2 : Foldback characteristic

FUNCTIONAL DESCRIPTION

The L4938N is based on the ST Microelectronics modular voltage regulator app. pach. Several outstanding features and auxiliary functions are provided to meet the requirements of supplying the microprocessor systems used in automotive applications.

Furthermore the device is suitable also in other applications requiring two stabilized voltages.

The modular approach allows other features and functions to be realized easily when required.

STANDBY REGULATOR

The standby regulator uses an Isolated Collector Vertical PNP transistor as the regulating element. This structure allows a very low dropout voltage at currents up to 50mA. The dropout operation of the standby regulator is maintained down to 2V input supply voltage. The output voltage is regulated up to the transient input supply voltage of 40V. This feature avoids functional interruptions which could be generated by overvoltage pulses.

The typical curve of the standby output voltage as a function of the input supply voltage is shown in fig. 1.

The current consumption of the device (quiescent current) is less than 250µA when output 2 is disabled (standby mode). The dropout voltage is controlled to reduce the quiescent current peak in the undervoltage region and to improve the transient response in this region.

The quiescent current is shown in fig. 2 as a function of the supply input voltage 2.

OUTPUT 2 VOLTAGE

The output 2 regulator uses the same output structure as the standby regulator, but rated for an output current of 500mA.

The output 2 regulator works in tracking mode with the standby output voltage as a reference voltage when the output 2 programming pin ADJ is connected to V₀₂. By connecting a resistor divider R₁, R₂ to the pin ADJ as shown in fig. 3, the output voltage 2 can be programmed to the value :

$$V_{O2} = V_{O1} (1 + R_1/R_2)$$

The output 2 regulator can be switched off via the Enable input.

If a fixed 5 regulation is required ADJ Pin has to be connected to V₀₂ Pin.



Figure 1 : Output Voltage vs. Input Voltage.

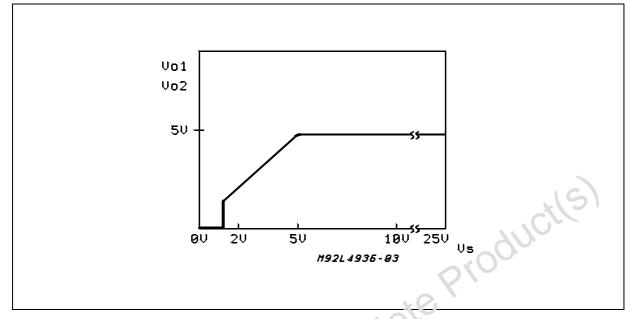
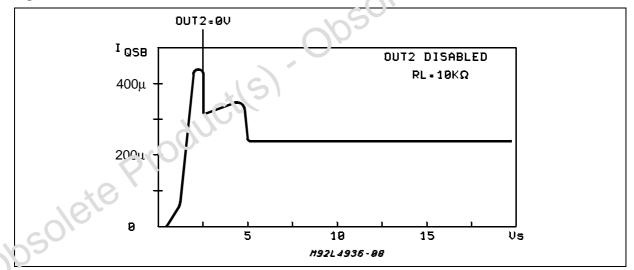
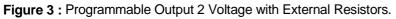
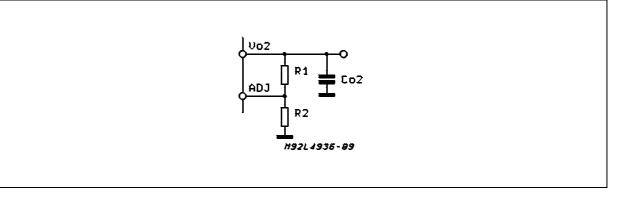


Figure 2 : Quiescent Current vs. Supply Voltage.









RESET CIRCUIT

The block circuit diagram of the reset circuit is shown in fig. 4. The reset circuit supervises the standby output voltage. The reset threshold of 4.7V is defined by the internal reference voltage and the standby output divider.

The reset pulse delay time t_{RD} , is defined by the charge time of an external capacitor C_T :

$$t_{RD} = \frac{C_T \times 2V}{2\mu A}$$

The reaction time of the reset circuit depends on the

discharge time limitation of the reset capacitor C_T and is proportional to the value of C_T .

The reaction time of the reset circuit increases the noise immunity. In fact, if the standby output voltage drops below the reset threshold for a time shorter than the reaction time t_{RR} , no reset output variation

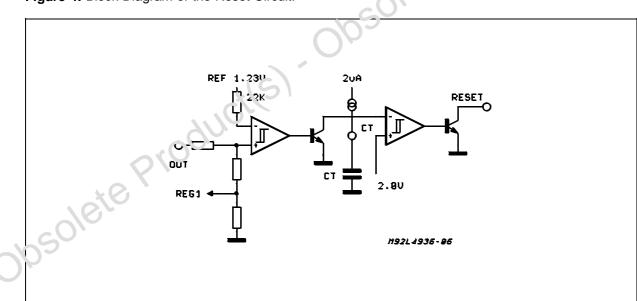
Figure 4: Block Diagram of the Reset Circuit.

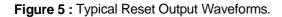
occurs. The nominal reset delay is generated for standby output voltage drops longer than the time necessary for the complete discharging of the capacitor C_T. This time is typically equal to $50\mu s$ if C_T = 100nF. The typical reset output waveforms are shown in fig. 5.

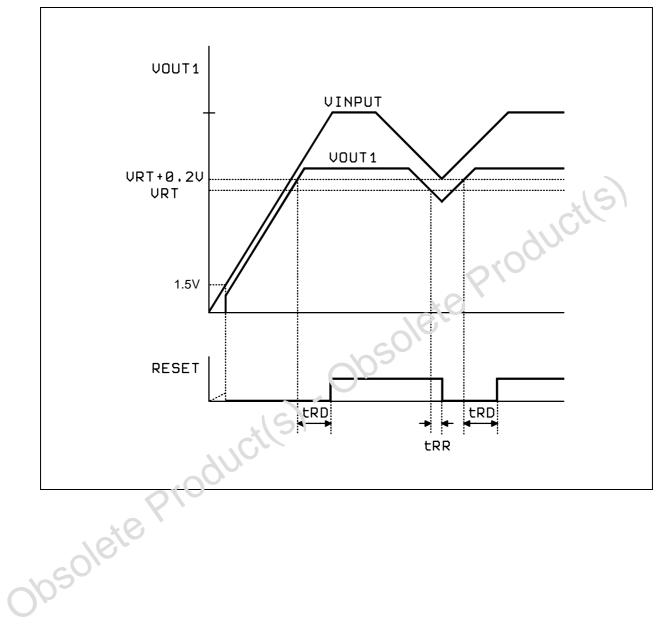
SENSE COMPARATOR

This circuit compares an input signal with an internal voltage reference of typically 1.23V. The use of an external voltage divider makes the comparator very flexible in the application. This function can be used to supervise the input voltage - either before or after the protection diode - and to give additional information to the microprocessor such as low voltage warnings.

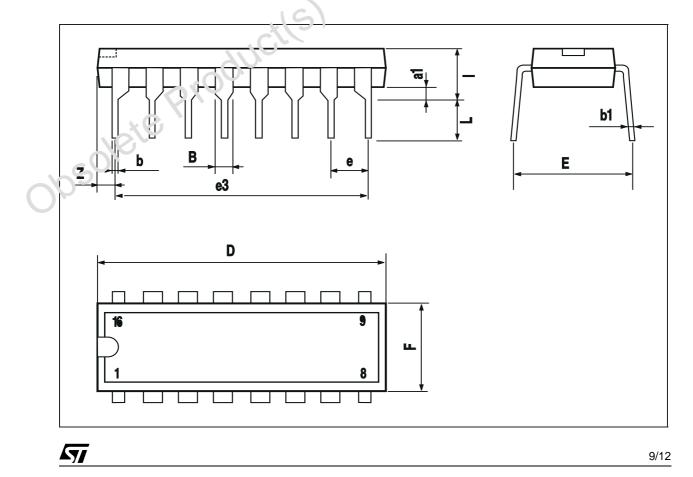
If this feature is not used SI and SO have to connected to GND. In this case the St-by quiescent current (14V) increases הסי 290µA to 300µA.





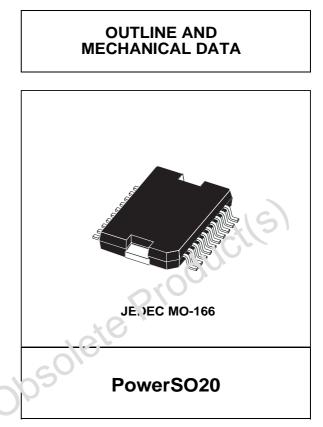


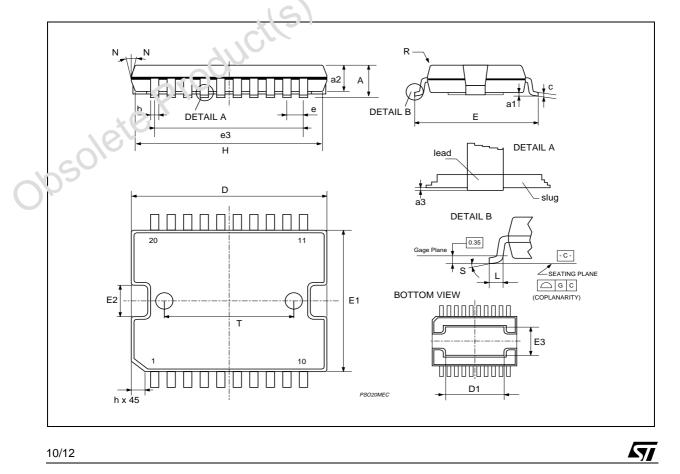
DIM.		mm			inch	
2	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
В	0.85		1.40	0.033		0.055
b		0.50			0.020	
b1	0.38		0.50	0.015		0.020
D			20.0			0.787
E		8.80			0.346	
е		2.54			0.100	
e3		17.78			0.700	
F			7.10			0.280
I			5.10			0.201
L		3.30			0.130	
z			1.27			0.050



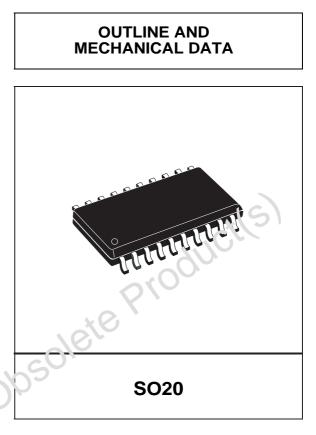
DIM.		mm		inch			
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Α			3.6			0.142	
a1	0.1		0.3	0.004		0.012	
a2			3.3			0.130	
a3	0		0.1	0.000		0.004	
b	0.4		0.53	0.016		0.021	
с	0.23		0.32	0.009		0.013	
D (1)	15.8		16	0.622		0.630	
D1	9.4		9.8	0.370		0.386	
E	13.9		14.5	0.547		0.570	
е		1.27			0.050		
e3		11.43			0.450		
E1 (1)	10.9		11.1	0.429		0.437	
E2			2.9			0.114	
E3	5.8		6.2	0.228		0.244	
G	0		0.1	0.000		0.004	
Н	15.5		15.9	0.610		0.626	
h			1.1			0.043	
L	0.8		1.1	0.031		0.043	
N			10° (r	max.)			
S			8° (n	nax.)			
Т		10			0.394		

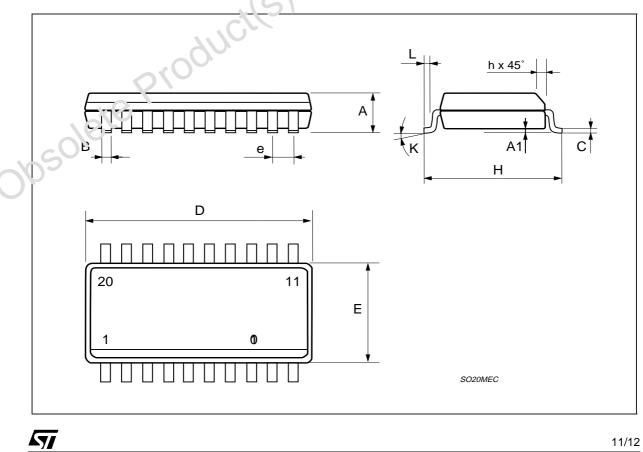
"D and F" do not include mold flash or protrusions.
Mold flash or protrusions shall not exceed 0.15 mm (0.006").
Critical dimensions: "E", "G" and "a3"





DIM.		mm		inch					
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.			
А	2.35		2.65	0.093		0.104			
A1	0.1		0.3	0.004		0.012			
В	0.33		0.51	0.013		0.020			
С	0.23		0.32	0.009		0.013			
D	12.6		13	0.496		0.512			
E	7.4		7.6	0.291		0.299			
е		1.27			0.050				
Н	10		10.65	0.394		0.419			
h	0.25		0.75	0.010		0.030			
L	0.4		1.27	0.016		0.050			
к		0° (min.)8° (max.)							





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